

Vishay High Power Products

Medium Power Thyristors (Stud Version), 50 A



TO-208AC (TO-65)

FEATURES

- · High current rating
- Excellent dynamic characteristics
- $dV/dt = 1000 V/\mu s$ option
- Superior surge capabilities
- · Standard package
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- · RoHS compliant

TYPICAL APPLICATIONS

- · Phase control applications in converters
- · Lighting circuits
- · Battery charges
- Regulated power supplies and temperature and speed control circuit
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		50	A			
I _{T(AV)}	T _C	94	°C			
I _{T(RMS)}		80	А			
1	50 Hz	1430	A			
I _{TSM}	60 Hz	1490	A			
l ² t	50 Hz	10.18	kA ² s			
1-1	60 Hz	9.30	KA-5			
V _{DRM} /V _{RRM}		100 to 1200	V			
t _q	Typical	110	μs			
T _J		- 40 to 125	°C			

PRODUCT SUMMARY

I_{T(AV)}
50 A

Document Number: 93711 Revision: 19-Sep-08

50RIA Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA			
	10	100	150				
50RIA	20	200	300				
	40	400	500				
	60	600	700	15			
	80	800	900				
	100	1000	1100				
	120	1200	1300				

Notes

⁽²⁾ For voltage pulses with $t_p \le 5 \text{ ms}$

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current at case temperature	I _{T(AV)}	180° sinusoidal conduction		50 94	A °C	
Maximum RMS on-state current	I _{T(RMS)}				80	A
With Mills of State Garrent	T(RMS)	t = 10 ms	No voltage		1430	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		1490	
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		1200	Α
· · · · · ·		t = 8.3 ms	reapplied	Sinusoidal half wave,	1255	
		No voltage	initial $T_J = T_J$ maximum	10.18		
Maximum I ² t for fusing		t = 8.3 ms	reapplied		9.30	kA ² s
		t = 10 ms	100 % V _{RRM}		7.20	
		t = 8.3 ms	reapplied		6.56	
Maximum l²√t for fusing	l²√t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		101.8	kA²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum		0.94	.,	
High level value of threshold voltage	V _{T(TO)2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.08	V	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		4.08	 0	
High level value of on-state slope resistance	r _{t2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			3.34	mΩ
Maximum on-state voltage	V_{TM}	I _{pk} = 157 A,	T _J = 25 °C		1.60	V
Maximum holding current	I _H	T_J = 25 °C, anode supply 22 V, resistive load, initial I_T = 2 A		200	mA	
Latching current	IL	Anode supply 6 V, resistive load			400	

 $^{^{(1)}}$ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/ μ s



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SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum rate of	V _{DRM} ≤ 600 V	dl/dt	$T_C = 125 ^{\circ}\text{C}$, $V_{DM} = \text{Rated } V_{DRM}$,	200	A/us
rise of turned-on current $V_{DRM} \le 1600 \text{ V}$			dI/dt Gate pulse = 20 V, 15 Ω , t_p = 6 μ s, t_r = 0.1 μ s maximum I _{TM} = (2 x rated dI/dt) A	100	Ανμδ
Typical delay time		t _d	T_C = 25 °C, V_{DM} = Rated V_{DRM} , I_{TM} = 10 A dc resistive circuit Gate pulse = 10 V, 15 Ω source, t_p = 20 μ s	0.9	
Typical turn-off time		tq	T_C = 125 °C, I_{TM} = 50 A, reapplied dV/dt = 20 V/ μ s dIr/dt = -10 A/ μ s, V_R = 50 V	110	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	200	V/us
off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	500 ⁽¹⁾	ν/μS

Note

 $^{^{(1)}}$ Available with dV/dt = 1000 V/ μ s, to complete code add S90 i.e. 50RIA120S90

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum, $t_p \le 5$	$T_J = T_J$ maximum, $t_p \le 5$ ms		W
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak positive gate current	I _{GM}			2.5	Α
Maximum peak positive gate voltage	+V _{GM}			20	V
Maximum peak negative gate voltage	-V _{GM}			10	V
		T _J = - 40 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	250	mA
DC gate current required to trigger	I _{GT}	T _J = 25 °C		100	
		T _J = 125 °C		50	
DC and well-are we wired to triumer	.,	T _J = - 40 °C		3.5	V
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C		2.5	
DC gate current not to trigger	I _{GD}	$T_J = T_J$ maximum, $V_{DRM} = Rated voltage$	Maximum gate current/voltage not to trigger is the maximum value	5.0	mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J$ maximum	which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.35	K/W		
Maximum thermal resistance, case to heatsink	R _{thCS}	CS Mounting surface, smooth, flat and greased		r./VV		
Allowable mounting torque		Non-lubricated threads	3.4 + 0 - 10 % (30)	N · m		
Allowable mounting torque		Lubricated threads	2.3 + 0 - 10 % (20)	(lbf · in)		
Approximate weight			28	g		
Approximate weight			1.0	OZ.		
Case style		See dimensions - link at the end of datasheet	TO-208A	C (TO-65)		

△R _{thJC} CONDUCTION	ON			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.078	0.057		
120°	0.094	0.098		
90°	0.120	0.130	$T_J = T_J$ maximum	K/W
60°	0.176	0.183		
30°	0.294	0.296		

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

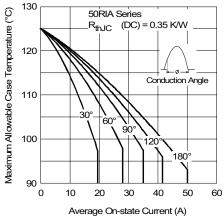


Fig. 1 - Current Ratings Characteristics

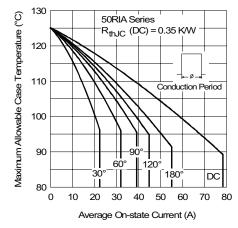


Fig. 2 - Current Ratings Characteristics



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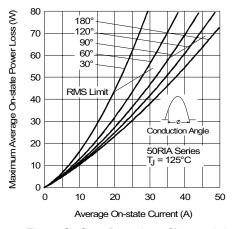


Fig. 3 - On-State Power Loss Characteristics

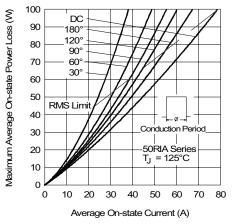


Fig. 4 - On-State Power Loss Characteristics

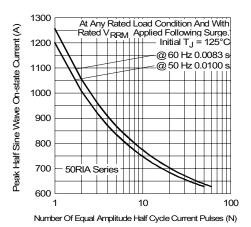


Fig. 5 - Maximum Non-Repetitive Surge Current

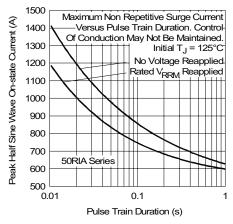


Fig. 6 - Maximum Non-Repetitive Surge Current

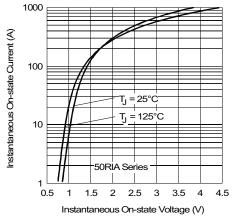


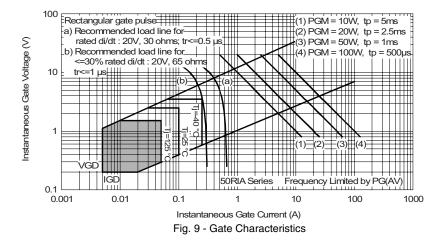
Fig. 7 - Forward Voltage Drop Characteristics

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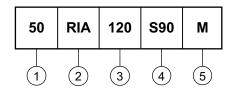


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Current code

2 - Essential part number

3 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

4 - Critical dV/dt:

• None = 500 V/µs (standard value)

• S90 = 1000 V/µs (special selection)

5 - None = Stud base TO-208AC (TO-65) 1/4" 28UNF-2A

• M = Stud base TO-208AC (TO-65) M6 x 1

LINKS TO RELAT	TED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95334

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